## VERWEY TRANSITION IN Fe<sub>3</sub>O<sub>4</sub> THIN FILMS: EFFECT OF SUBSTRATE TEMPERATURE

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Fe<sub>3</sub>O<sub>4</sub> with spinel structure is a promising material for spintronic devices because of its half metallic nature and high Curie temperature of 853 K. Additionally, Fe<sub>3</sub>O<sub>4</sub> shows curious metal-insulator transition at temperature of  $T_v = 120$  K, named as Verwey transition, where magnetite transforms from cubic to monoclinic crystal structure due to freezing of electron hopping. [1-3] Observation of the Verwey transition by means of magnetic study is an interesting way to deduce the purity of films since this transition is signature of Fe<sub>3</sub>O<sub>4</sub>. Fe<sub>3</sub>O<sub>4</sub> thin films were deposited by PLD at various substrate temperatures (T<sub>s</sub>) on fused quartz substrates. The study showed that the substrate temperature play an important role in determining the composition and structural properties of the films. Films with  $(\ell\ell 0)$  and  $(\ell\ell\ell)$  orientations could be achived by varying T<sub>s</sub>. The  $4\pi M_s$  value does not show monotonous increase with T<sub>s</sub> but goes through a maximum value for T<sub>s</sub> of 350° C. Temperature dependence of magnetization (M-T) study shows that, as T<sub>s</sub> increases from RT to 850° C, the position of Verwey transition temperature changes from 70 K to 120 K and then to spread over a wider temperature range. This raises the possibility of controlling the properties in Fe<sub>3</sub>O<sub>4</sub> films by varying the T<sub>s</sub> and higher T<sub>s</sub> is essential for the application to spin-electronics device. The origin of the Verwey transition and its shift will be discussed on the basis of these results.

- [1] A. Yanase, K. Siratori, J. Phys. Soc. Jap. **53**, 312 (1984)
- [2] G.Hu and Y.Suzuki, Phys. Rev. Lett. **89**, 276601 (2002)
- [3] L. R. Bickford, Jr., Rev. Mod. Phys. 25, 75 (1953)